EE 247B/ME 218: Introduction to MEMS Design

Module 17: Noise & MDS



EE C247B - ME C218 Introduction to MEMS Design Fall 2015

Prof. Clark T.-C. Nguyen

Dept. of Electrical Engineering & Computer Sciences
University of California at Berkeley
Berkeley, CA 94720

Module 17: Noise & MDS

EEC247B/MEC218: Introduction to MEMS Design

.ecM 17

C. Nguye

11/18/0

UC Berkeley

Lecture Outline

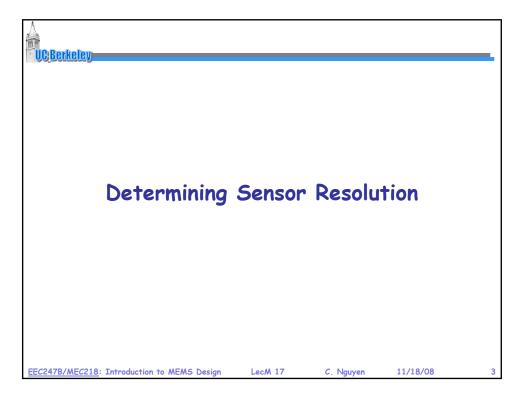
- Reading: Senturia Chpt. 16
- Lecture Topics:
 - ♦ Minimum Detectable Signal
 - ♥ Noise
 - Circuit Noise Calculations
 - ◆ Noise Sources
 - **◆** Equivalent Input-Referred Noise
 - **⇔** Gyro MDS
 - **←** Equivalent Noise Circuit
 - **★** Example ARW Determination

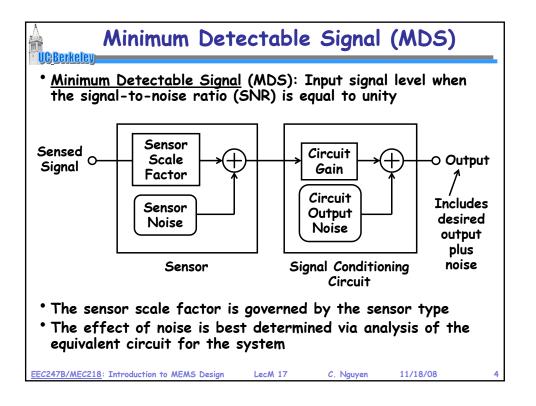
EEC247B/MEC218: Introduction to MEMS Design

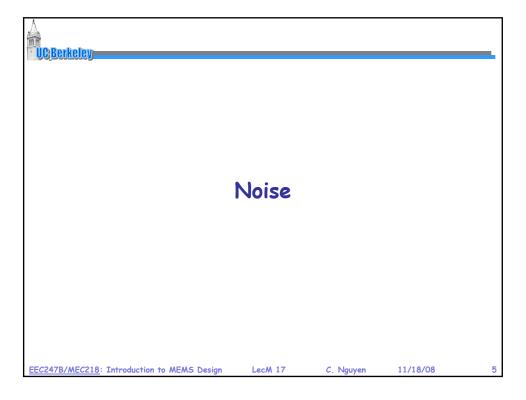
LecM 17

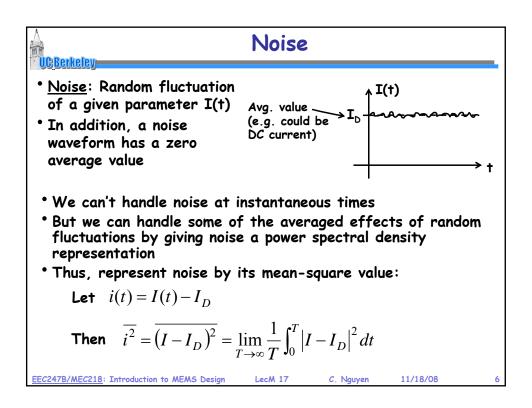
C. Nguyen

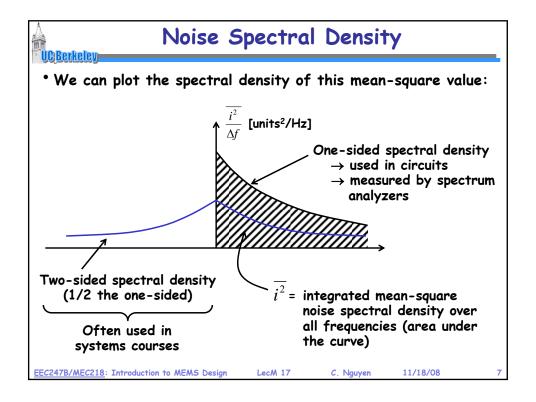
11/18/08

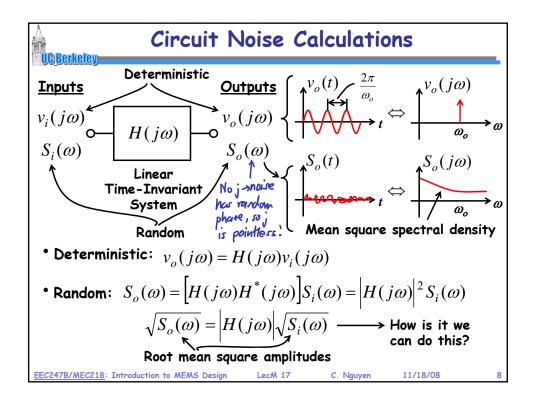


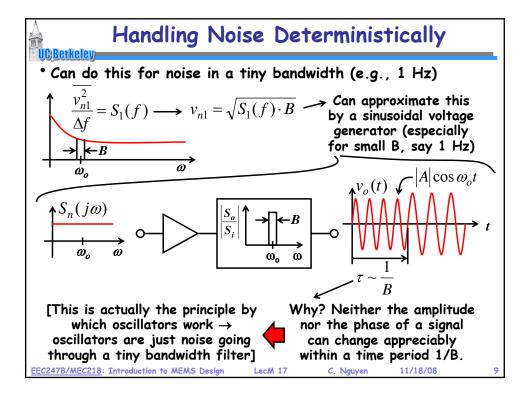


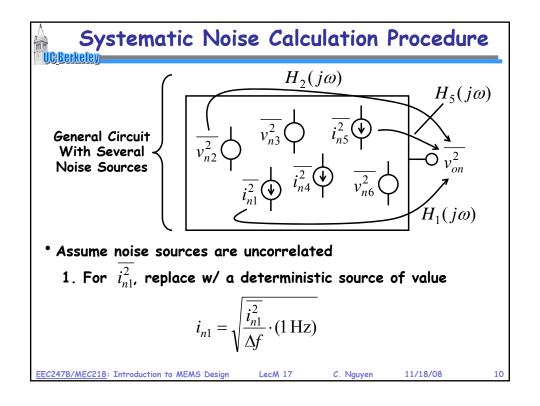












Systematic Noise Calculation Procedure

- 2. Calculate $v_{on1}(\omega)$ = $i_{n1}(\omega)H(j\omega)$ (treating it like a deterministic signal)
- 3. Determine $\overline{v_{on1}^2} = \overline{i_{n1}^2} \cdot \left| H(j\omega) \right|^2$ 4. Repeat for each noise source: $\overline{i_{n1}^2}$, $\overline{v_{n2}^2}$, $\overline{v_{n3}^2}$
- 5. Add noise power (mean square values)

$$\overline{v_{onTOT}^2} = \overline{v_{on1}^2} + \overline{v_{on2}^2} + \overline{v_{on3}^2} + \overline{v_{on4}^2} + \cdots$$

$$v_{onTOT} = \sqrt{\overline{v_{on1}^2} + \overline{v_{on2}^2} + \overline{v_{on3}^2} + \overline{v_{on4}^2} + \cdots}$$

Total rms value

Noise Sources

Thermal Noise

UC Berkeley

- Thermal Noise in Electronics: (Johnson noise, Nyquist noise)
 - Produced as a result of the thermally excited random motion of free e-'s in a conducting medium
 - \$Path of e's randomly oriented due to collisions
- * Thermal Noise in Mechanics: (Brownian motion noise)
 - Thermal noise is associated with all dissipative processes that couple to the thermal domain
 - Any damping generates thermal noise, including gas damping, internal losses, etc.
- Properties:
 - \$ Thermal noise is white (i.e., constant w/ frequency)
 - \$ Proportional to temperature
 - ♦ Not associated with current
 - Present in any real physical resistor

EEC247B/MEC218: Introduction to MEMS Design

.ecM 17

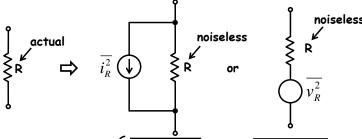
C. Nguyen

11/18/0

13

Circuit Representation of Thermal Noise

* Thermal Noise can be shown to be represented by a series voltage generator $\overline{v_R^2}$ or a shunt current generator $\overline{i_R^2}$



Note: These are one-sided mean-square spectral densities! To make them 2-sided, must divide by 2.

 $\frac{\overline{i_R^2}}{\Delta f} = \frac{4kT}{R}$

 $\frac{\overline{v_R^2}}{\Delta f} = 4kTR$

where $4kT = 1.66x10^{-20}V \cdot C$ and where these are spectral densities.

EEC247B/MEC218: Introduction to MEMS Design

LecM 17

C. Nguyen

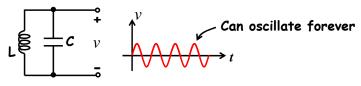
11/18/08

14

Noise in Capacitors and Inductors?

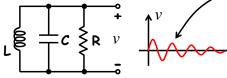
UC Berkeley

- Resistors generate thermal noise
- Capacitors and inductors are noiseless → why?



• Now, add a resistor:

Decays to zero



But this violates the laws of thermodynamics, which require that things be in constant motion at finite temperature

Need to add a forcing function, like a noise voltage $\,\nu_{R}^{2}\,$ to keep the motion going \to and this noise source is associated with R

EEC247B/MEC218: Introduction to MEMS Design

_ecM 17

C. Nguyen

11/18/08

15

Why 4kTR?

UC Berkeley

- Why is $\overline{v_R^2} = 4kTR\Delta f$ (a heuristic argument)
- The <u>Equipartition Theorem of Statistical Thermodynamics</u> says that there is a mean energy (1/2)kT associated w/ each degree of freedom in a given system
- An electronic circuit possesses two degrees of freedom:
 - Scurrent, i, and voltage, v
 - ♦ Thus, we can write:

Energy

can write:
$$\frac{1}{2}Li^{2} = \frac{1}{2}k_{B}T$$
, $\frac{1}{2}Cv^{2} = \frac{1}{2}k_{B}T$

Similar expressions can be written for mechanical systems
 For example: for displacement, x

Spring constant
$$\frac{1}{2}k\overline{x^2} = \frac{1}{2}k_BT$$

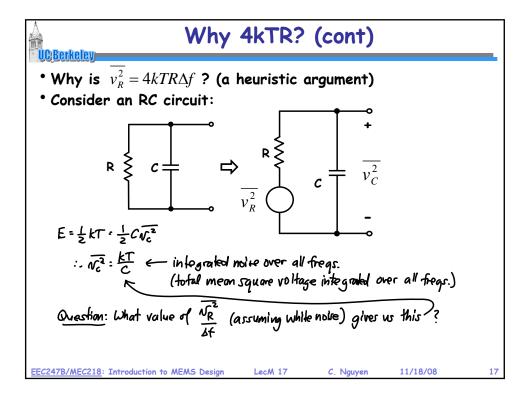
EEC247B/MEC218: Introduction to MEMS Design

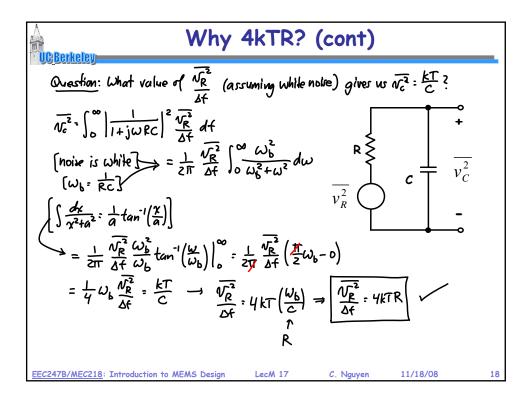
LecM 17

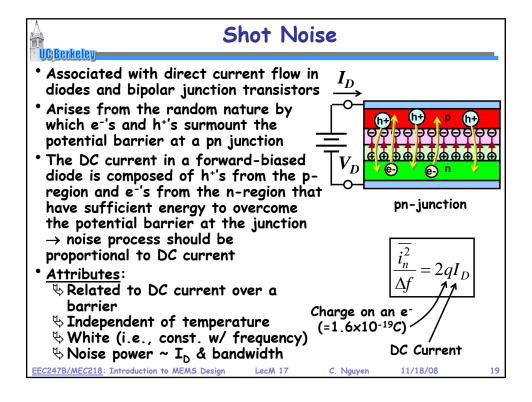
C. Nguyen

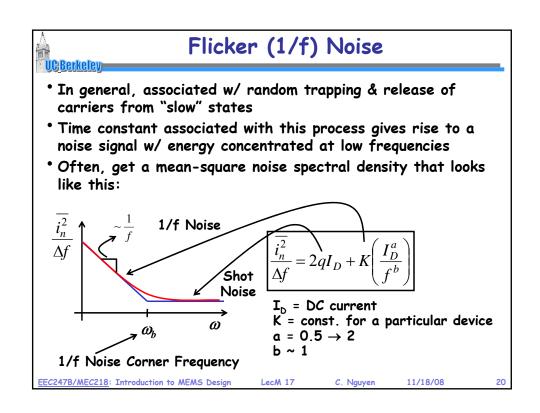
/18/08

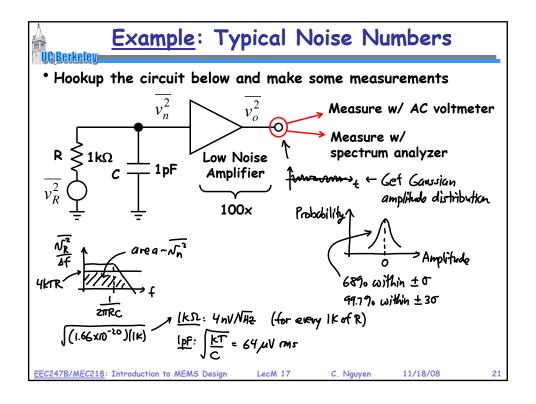
10

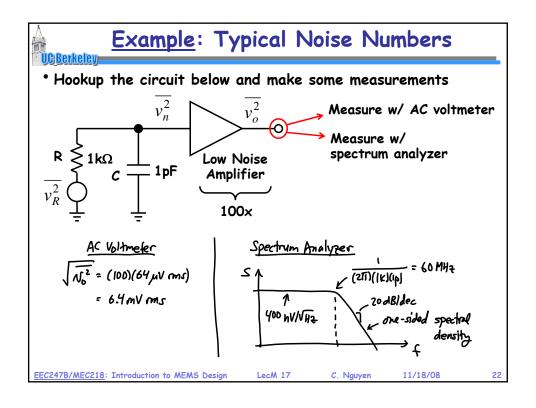


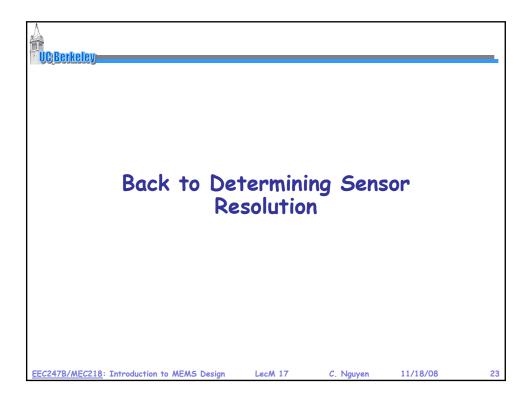


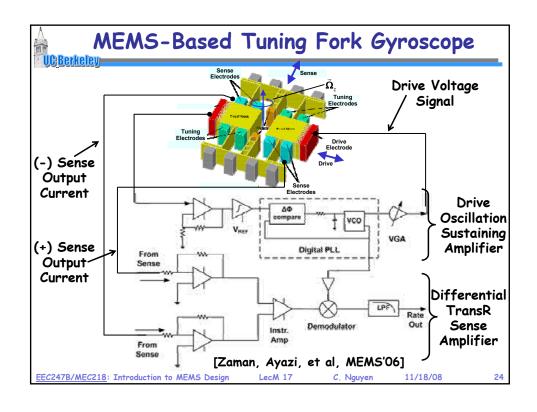


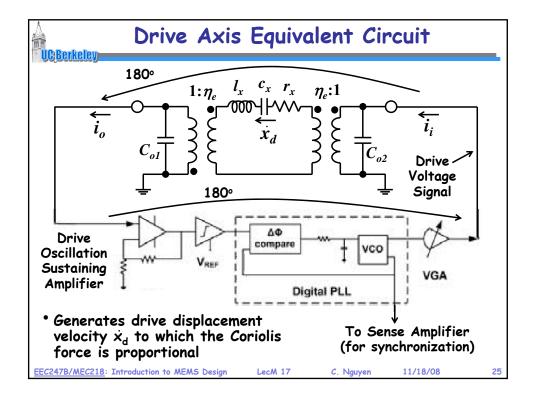


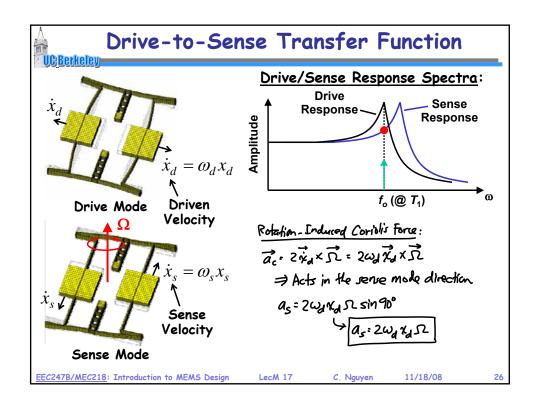


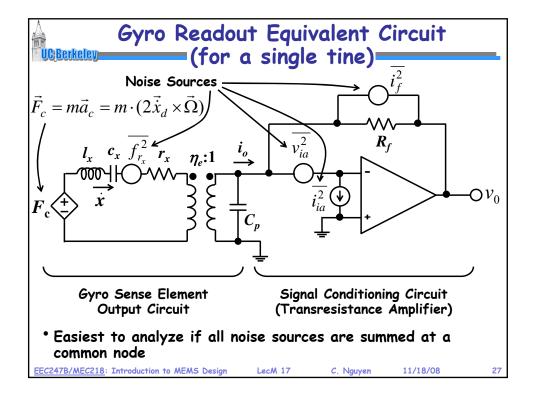


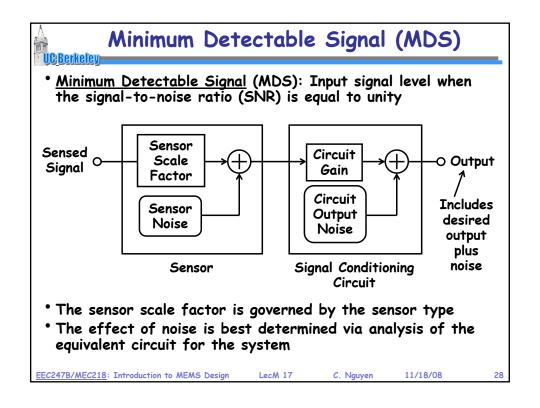


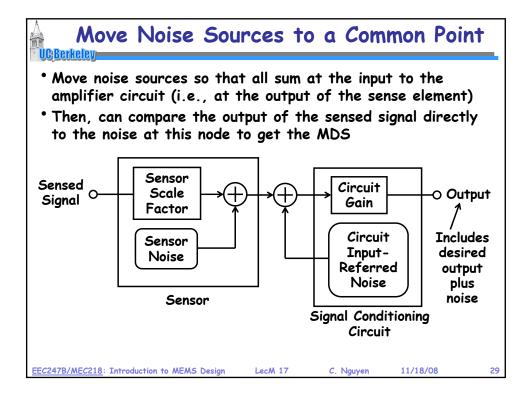


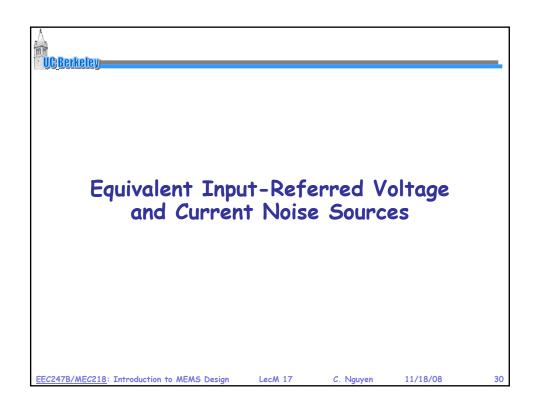






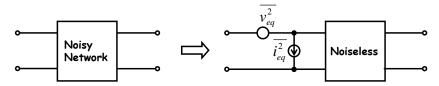








• Take a noisy 2-port network and represent it by a noiseless network with input ν and i noise generators that generate the same total output noise



- Remarks:
 - 1. Works for linear time-invariant networks
 - 2. v_{eq} and i_{eq} are generally correlated (since they are derived from the same sources)
 - 3. In many practical circuits, one of $v_{\rm eq}$ and $i_{\rm eq}$ dominates, which removes the need to address correlation
 - 4. If correlation is important \rightarrow easier to return to original network with internal noise sources

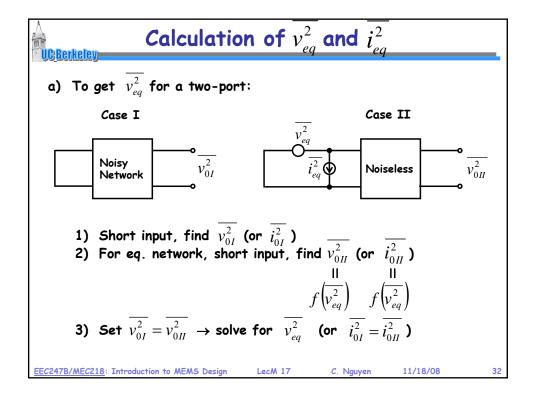
EEC247B/MEC218: Introduction to MEMS Design

CM 17

. Nguyen

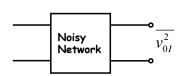
11/18/08

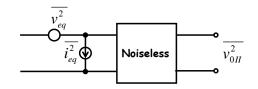
31





b) To get $\overline{i_{ea}^2}$ for a 2-port:





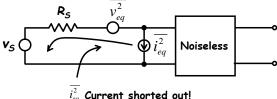
- 1) Open input, find $\overline{v_{0I}^2}$ (or $\overline{i_{0I}^2}$)
- 2) Open input for eq. circuit, find $\overline{v_{0II}^2}$ (or $\overline{i_{0II}^2}$)

 3) Set $\overline{v_{0I}^2} = \overline{v_{0II}^2} \left(\overline{i_{eq}^2}\right) \rightarrow \text{solve for } \overline{i_{eq}^2} \left(\text{or } \overline{i_{0I}^2} = \overline{i_{0II}^2} \left(\overline{i_{eq}^2}\right)\right)$
- * Once the equivalent input-referred noise generators are found, noise calculations become straightforward as long as the noise generators can be treated as uncorrelated

EC247B/MEC218: Introduction to MEMS Design

Cases Where Correlation Is Not Important

- There are two common cases where correlation can be ignored:
 - 1. Source resistance R_s is small compared to input resistance $R_i \rightarrow i.e.$, voltage source input
 - 2. Source resistance R_s is large compared to input resistance $R_i \rightarrow i.e.$, current source input
 - 1) R_s = small (ideally = 0 for an ideal voltage source):

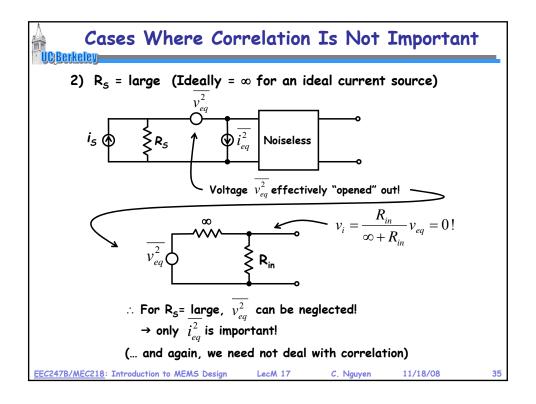


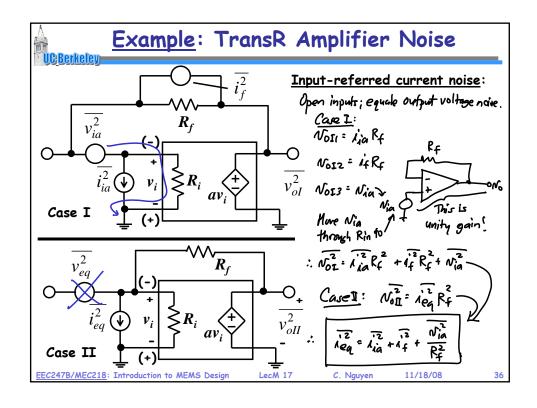
 i_{eq}^2 Current shorted out!

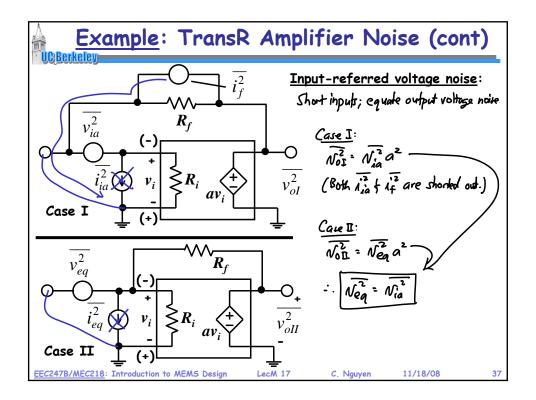
 \therefore For R_s= small, $\overline{i_{eq}^2}$ can be neglected \Rightarrow only $\overline{v_{eq}^2}$ is important! (Thus, we need not deal with correlation)

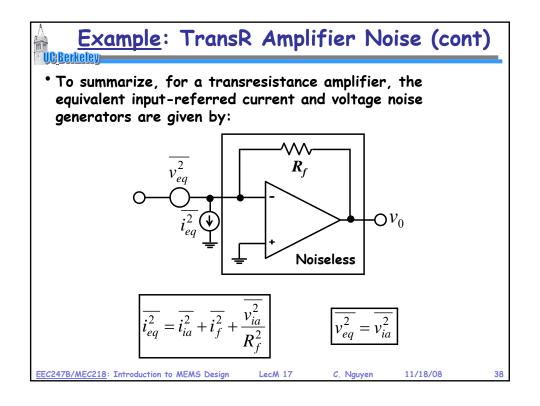
EC247B/MEC218: Introduction to MEMS Design

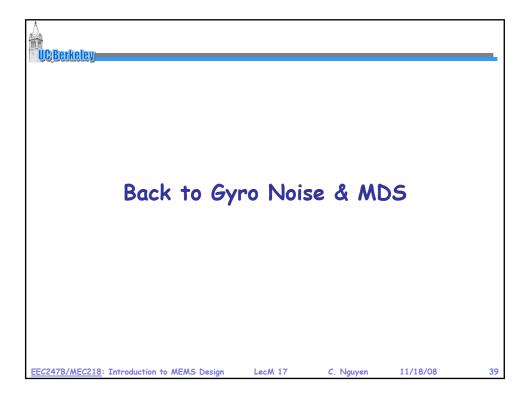
Copyright © 2015 Regents of the University of California

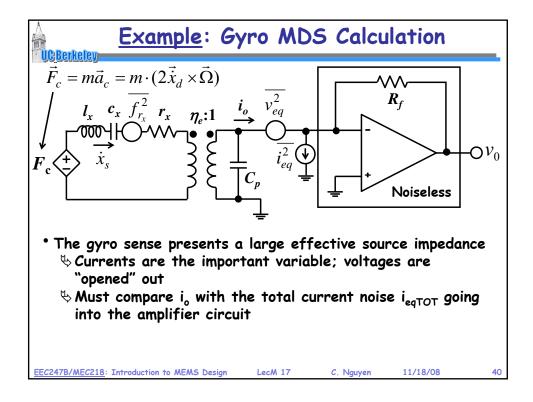


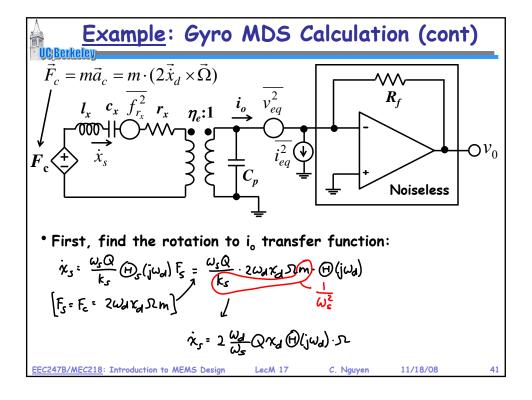


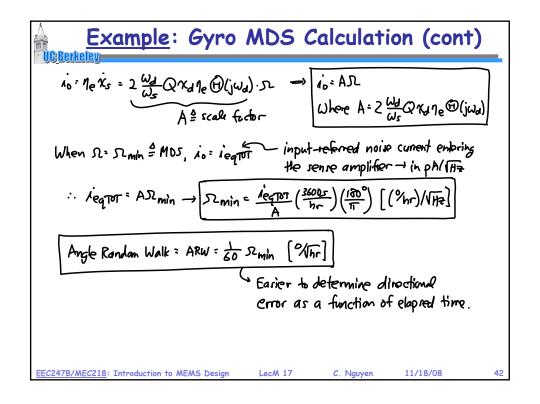


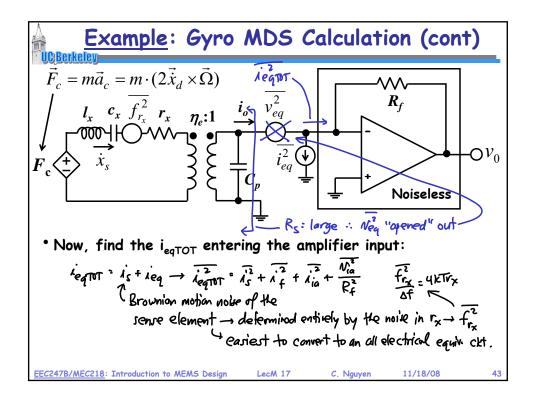


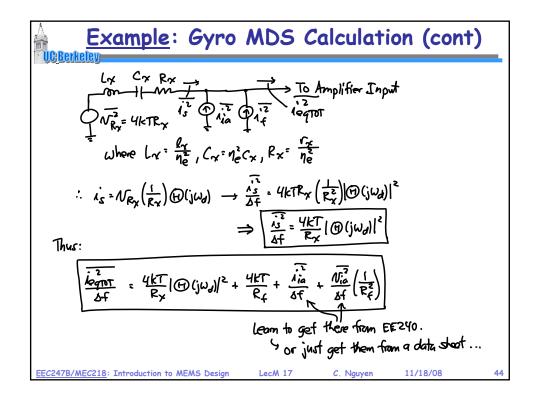


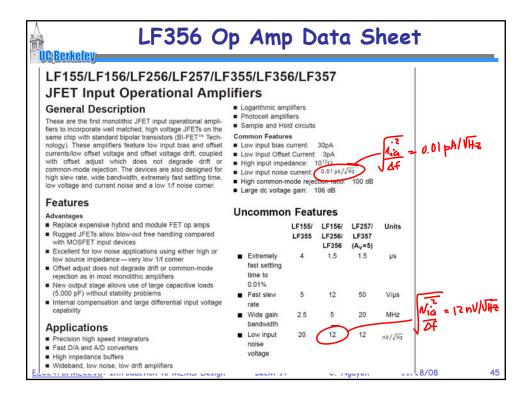


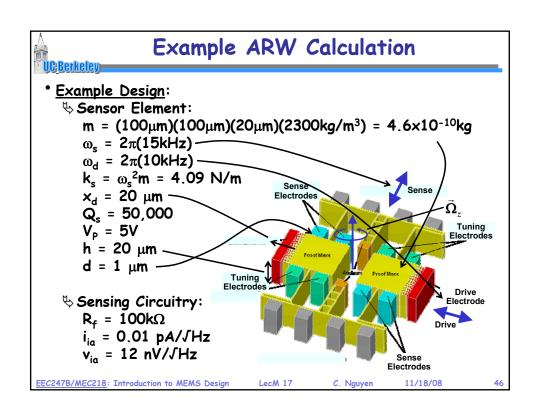












Example ARW Calculation (cont)

UBBerkeley

Get rotation rate to output current scale factor:

$$A = 2 \frac{Ud}{US} Q_{X}U \eta_{e} | \Theta(j\omega_{d})| = 2 \frac{(OK)}{ISK} (SOK) (20\mu)(S)(2000 E_{0})(0.000024) = 2.83 \times 10^{-12} C$$

$$\Theta(j\omega_{d}) = \frac{(j\omega_{d})(\omega_{S}/OS)}{-\omega_{d}^{2} + j(\omega_{d}\omega_{S})} = \frac{j(IOK)(ISK)/(SOK)}{(ISK)^{2} + j(IOK)(ISK)} = \frac{j(3K)}{I \cdot 25 \times 10^{-6} + j(3K)}$$

$$\Rightarrow | \Theta(j\omega_{d})| = \frac{3k}{\sqrt{(I \cdot 25 \times 10^{-6})^{2} + (3K)^{2}}} = 0.0000244$$

$$= \frac{3K}{2K} = \frac{C_{0}}{A} = \frac{E_{0} hWp}{A} = \frac{E_{0}(20\mu)(IOD_{d})}{(I\mu)^{2}} = 2000 E_{0} \Rightarrow \eta_{e} = V_{p} \frac{3C}{2K} = S(2000 E_{0})$$

Assume electrical covers as as sylvio from the Whole sidewall.

Then, get noise:

$$\frac{iQ_{1}}{A} = \frac{V_{1}}{K_{2}} | \Theta(j\omega_{d})|^{2} + \frac{V_{1}K_{1}}{K_{2}} + \frac{Aia}{Af} + \frac{N_{10}^{-2}}{Af} \left(\frac{1}{K_{2}^{2}}\right)$$

EEC247B/MEC218: Introduction to MEMS Design Leck 17 C. Nguyen 11/18/08 47

Example ARW Calculation (cont)

$$\begin{bmatrix}
R_{Y_{4}} = \frac{\omega_{s}m}{Q_{s}^{9}l_{e}^{2}} = \frac{2\pi\Gamma(15K)(46X10^{-10})}{(50K)(8.85\%10^{-9})^{2}} = 110.6kD
\end{bmatrix}$$

$$\frac{\lambda_{eq10T}}{\Delta f} = \frac{(1.66\times10^{-20})}{(110.6K)} (0.000024)^{2} + \frac{(1.66\times10^{-20})}{1M} + \frac{(0.01p)^{2}}{(1M)^{2}} + \frac{(12n)^{2}}{(1M)^{2}}$$

$$\frac{\lambda_{eq10T}}{\lambda_{eq10T}} = \frac{(1.66\times10^{-25})^{2}}{(110.6K)} + \frac{\lambda_{eq10T}}{\lambda_{eq10T}} = \frac{\lambda$$

What if
$$\omega_{d} = \omega_{s}$$
?

If $\omega_{d} = \omega_{s} = 15KH^{2}$, then $|\Theta|(j\omega_{d})| = 1$ and

$$A = 2 \frac{\omega_{d}}{\omega_{s}} C_{s} K_{d} \eta_{e} |\Theta|(j\omega_{d})| = 2 C_{s} K_{d} \eta_{e} = 2(50K)(20\mu)(5)(2000 \epsilon_{0}) = \frac{1.77 \times 10^{-7} \text{C}}{1.000 \epsilon_{0}} = \frac{1.66 \times 10^{-20} \text{A}}{1.000 \epsilon_{0}} + \frac{1.66 \times 10^{-20} \text{A}}{1.000 \epsilon_{0}} + \frac{1.2 \text{A}}{1.000 \epsilon_{0}} = \frac{1.77 \times 10^{-7} \text{C}}{1.000 \epsilon_{0}} =$$